# EFFECT OF Li<sub>2</sub>CO<sub>3</sub> ADDITION ON THE PIEZOELECTRIC AND DIELECTRIC PROPERTIES OF Pb<sub>0.93</sub>La<sub>0.02</sub>Sr<sub>0.05</sub>(Zr<sub>0.52</sub>Ti<sub>0.48</sub>)O<sub>3</sub> CERAMICS

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## EFFECT OF Li $_2$ CO $_3$ ADDITION ON THE PIEZOELECTRIC AND DIELECTRIC PROPERTIES OF Pb $_{0.93}$ La $_{0.02}$ Sr $_{0.05}$ (Zr $_{0.52}$ Ti $_{0.48}$ )O $_3$ CERAMICS

by

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Thesis submitted in fulfillment of the requirements for the degree of Master of Science

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### TABLE OF CONTENTS

	Page
ACKNOWLEDGEMENTS	ii
TABLE OF CONTENTS	iii
LIST OF TABLES	vii
LIST OF FIGURES	viii
LIST OF SYMBOLS	xii
LIST OF ABBREVIATIONS	xiii
ABSTRAK	xiv
ABSTRACT	XV
CHAPTER ONE: INTRODUCTION	
1.1 Background	1
1.2 Problem Statement	5
1.3 Objectives of the Research	7
1.4 Thesis Structure	8
CHAPTER TWO: LITERATURE REVIEW	
2.1 Introduction	10
2.2 Piezoelectricity	14
2.3 Perovskite Structure	19
2.4 Dielectric Properties	21
2.4.1 Dielectric Constant	21
2.4.2 Loss Tangent	22
2.5 Piezoelectric Properties	23
2.5.1 Electromechanical Coupling Factor	24

	2.5.2 Piezoelectric Constant	25
	2.5.3 Quality Mechanical Factor	26
2.6	Piezoelectric Material	26
	2.6.1 Dopants to Improve Piezoelectric Properties	31
	2.6.1 (a) Lanthanum Doped Lead Zirconate Titanate	34
	2.6.1 (b) Lanthanum and Strontium Doped Lead Zirconate Titanate	36
2.7	High Temperature Perovskite Phase Formation in PZT Ceramics	41
2.8	Summary	45
CHAI	PTER THREE: EXPERIMENTAL METHOD	
3.1	Introduction	46
3.2	Raw Materials	48
	3.2.1 Particle Size	49
	3.2.2 Purity	49
3.3	Stage 1: Synthesis of Pure PZT and Doped PZTs with La <sup>3+</sup> and Sr <sup>2+</sup>	50
	3.3.1 Pure PZT	50
	3.3.2 Doped PZT	51
3.4	Stage 2: Doped PLSZT with Li <sub>2</sub> CO <sub>3</sub>	54
	3.4.1 Milling & Mixing	54
	3.4.2 Thermal Analysis	55
	3.4.3 Powder Compaction	56
	3.4.4 Sintering	56
3.5	Characterization	57
	3.5.1 XRD Analysis	57
	3.5.2 FESEM Analysis	58

	3.5.3 Density Measurement	59
3.6	Dielectric and Piezoelectric Properties	60
	3.6.1 Poling	60
	3.6.2 Piezoelectric Constant	61
	3.6.3 Electromechanical Coupling Factor	62
	3.6.4 Quality Mechanical Factor	63
	3.6.5 Dielectric Permittivity and Loss Tangent	63
CHAI	PTER FOUR: RESULTS AND DISCUSSION	
4.1	Raw Material	64
	4.1.1 Lead Oxide	64
	4.1.2 Zirconium Oxide	66
	4.1.3 Titanium Oxide	68
	4.1.4 Strontium Carbonate	70
	4.1.5 Lanthanum Hydroxide	72
	4.1.6 Lithium Carbonate	74
4.2	Stage 1: Effect of $\mathrm{Sr}^{2+}$ and $\mathrm{La}^{3+}$ on Piezoelectric and Dielectric Properties of PZT Ceramics	76
	4.2.1 Phase Analysis of Sr <sup>2+</sup> and La <sup>3+</sup> Doped PZT Ceramics	77
	4.2.2 Microstructure Analysis of Sr <sup>2+</sup> and La <sup>3+</sup> Doped PZT Ceramics	79
	4.2.3 Density and Porosity of Sr <sup>2+</sup> and La <sup>3+</sup> Doped PZT Ceramics	80
	4.2.4 Piezoelectric Properties of Sr <sup>2+</sup> and La <sup>3+</sup> Doped PZT Ceramics	82
	4.2.5 Dielectric Properties of Sr <sup>2+</sup> and La <sup>3+</sup> Doped PZT Ceramics	84
	4.2.6 Summary	85
4.3	Stage 2: Effect of Li <sub>2</sub> CO <sub>3</sub> on the PLSZT Ceramics	86

4.3.1 Thermal Analysis of Li <sub>2</sub> CO <sub>3</sub> Doped PLSZTCeramics	86
4.3.2 Characterization of Li <sup>+</sup> Doped PLSZT Ceramics	89
4.3.2 (a) XRD Analysis of Li <sup>+</sup> Doped PLSZTCeramics	89
4.3.2 (b) FESEM Analysis of Li <sup>+</sup> Doped PLSZT Ceramics	91
4.3.2 (c) Density and Porosity of Li <sup>+</sup> Doped PLSZT Ceramics	93
4.3.3 Piezoelectric and Dielectric Properties of Li <sup>+</sup> Doped PLSZT Ceramics	94
4.3.3 (a) Piezoelectric Properties of Li <sup>+</sup> Doped PLSZT Ceramics	94
4.3.3 (b) Dielectric Properties of Li <sup>+</sup> Doped PLSZT Ceramics	98
CHAPTER FIVE: CONCLUSION AND RECOMENDATION	
5.1 Conclusion	104
5.2 The Recommendation for Future Work	105
REFERENCES	106
APPENDICES	

### LIST OF TABLES

		Page
Table 2.1	Piezoelectric and dielectric properties of doped PZT ceramics	33
Table 2.2	Piezoelectric and dielectric properties of La <sup>3+</sup> doped PZT	38
Table 2.3	Piezoelectric and dielectric properties of Li <sub>2</sub> CO <sub>3</sub> doped PZT ceramics	40
Table 3.1	Sample codes and their chemical formulas use in this research	48
Table 3.2	Summary of raw powder used to synthesized PZT based ceramics (all the chemicals were supplied by Sigma Aldrich)	48
Table 3.3	Stoichometric calculation for batch preparation of pure PZT	51
Table 3.4	Stoichometric calculation for batch preparation of PSZT	52
Table 3.5	Stoichometric calculation for batch preparation of pure PLZT	52
Table 3.6	Stoichometric calculation for batch preparation of pure PLSZT	53
Table 3.7	Stoichometric calculation for batch preparation of $Pb_{0.93}Lr_{0.02}Sr_{0.05}(Zr_{0.52}Ti_{0.48})O_3+x\ Li_2CO_3$	55
Table 4.1	Effect of various dopants on the piezoelectric and dielectric properties of undoped and doped PZT ceramics	86
Table 4.2	Effect of Li <sub>2</sub> CO <sub>3</sub> dopants on the piezoelectric and dielectric properties of PLSZT ceramics at 850 °C	103

### LIST OF FIGURES

		Page
Figure 2.1	Schematic presentation of different types of polarization mechanisms; a) Electronic, b) Ionic, c) Dipolar, and d) Interfacial (Richerson et al., 2005)	12
Figure 2.2	The ion displacement in BaTiO <sub>3</sub> of [100] projection (Carter & Norton, 2007)	13
Figure 2.3	Schematic presentation of a) Direct piezoelectric effect and b) Converse piezoelectric effect in piezoelectric materials (Yang, 2004)	15
Figure 2.4	Piezoelectric and subgroups on the basis of symmetry (Haertling, 1999)	16
Figure 2.5	a) Ionic displacement and b) domain structure of ferroelectric materials (Xu, 2013)	17
Figure 2.6	Polarization P and electric field E hysteresis loop in ferroelectric material (Xu, 2013)	19
Figure 2.7	Perovskite structure (Galasso, 2013)	20
Figure 2.8	A parallel-plate capacitor a) with dielectric material and b) without dielectric material (Richerson et al., 2005)	22
Figure 2.9	Axis notations for piezoelectric ceramic (Carter & Norton, 2007)	24
Figure 2.10	The mechanical force and charge relationship as 33 mode in piezoelectric property (Saadon & Sidek, 2011)	26
Figure 2.11	Perovskite structure of PZT (Haertling, 1999)	27
Figure 2.12	Lead zirconate titanate phase diagram (Thomas, 1989)	28
Figure 2.13	Phase transformation of PbTiO <sub>3</sub> -PbZrO <sub>3</sub> near MPB (Damjanovic & Newnham, 1992)	29
Figure 2.14	Properties of PbTiO <sub>3</sub> -PbZrO <sub>3</sub> near MPB (Jaffe et al., 1955)	30
Figure 2.15	Reactions involved in the Phase formation in PZT system at different temperature (Necira et al., 2013)	42
Figure 3.1	Flowchart of the experimental procedure adopted throughout in this research	47

Figure 3.2	Schematic representation of sintering cycle for PLSZLT	57
Figure 3.3	a) Display meter of $d_{33}$ Piezometer and shaker b) upper view , and c) side view of shaker	61
Figure 3.4	Impedance spectrometer	62
Figure 4.1	XRD pattern of lead oxide powder ICDD No.00-005-0561	65
Figure 4.2	FESEM image of lead oxide powder	65
Figure 4.3	Particle size distribution of lead oxide powder	66
Figure 4.4	XRD pattern of zirconium oxide powder ICDD No. 00-037-1484	67
Figure 4.5	FESEM image of zirconium oxide powder	67
Figure 4.6	Particle size distribution of Zirconium oxide powder	68
Figure 4.7	XRD pattern of titanium oxide powder ICDD No.00-021-1272	69
Figure 4.8	FESEM image of titanium oxide powder	69
Figure 4.9	Particle size distribution of titanium oxide powder	70
Figure 4.10	XRD pattern of strontium carbonate powder ICDD No. 01-084-1778	71
Figure 4.11	FESEM image of strontium carbonates powder	71
Figure 4.12	Particle size distributions of strontium carbonate powder	72
Figure 4.13	XRD pattern of lanthanum hydroxide powder ICDD No. 14507-19-8	73
Figure 4.14	FESEM image of lanthanum hydroxide powder	73
Figure 4.15	Particle size distribution of lanthanum hydroxide powder	74
Figure 4.16	XRD pattern of lithium carbonate powder ICDD No.01-087-0728	75
Figure 4.17	FESEM image of lithium carbonate powder	75
Figure 4.18	Particle size distribution of Lithium Carbonate powder	76
Figure 4.19	XRD pattern of sintered PZT ceramics with different dopants a) PZT, b) PSZT, c) PLZT, and d) PLSZT	78

Figure 4.20	FESEM micrograph of PZT ceramics with different dopants: a) PZT, b) PSZT, c) PLZT, and d) PLSZT	80
Figure 4.21	Density of pure PZT and doped PZT with different dopants	81
Figure 4.22	Piezoelectric constant $(d_{33})$ of pure PZT and doped PZT ceramics	83
Figure 4.23	Electromechanical coupling factor $(k_p)$ of pure PZT and doped PZT	83
Figure 4.24	Relative permittivity of pure PZT and Doped PZT	85
Figure 4.25	TGA/DTA curves for PLSZLiT powder	87
Figure 4.26	The XRD pattern of PLSZLiT ceramics sintered at different temperature: a) 800 °C, b) 850 °C, and c) 900 °C	88
Figure 4.27	XRD patterns of PLSZT specimens with different Li <sub>2</sub> CO <sub>3</sub> concentration sintered at 850 °C: a) PLSZT (0 mol%), b) PLSZLiT1 (0.5 mol%), c) PLSZLiT2 (0.7 mol%), d) PLSZLiT3 (0.9 mol%), and e) PLSZLiT4 (1 mol%)	89
Figure 4.28	Enlarge pictures of peaks splitting around 44°.a) PLSZT (0), b) PLSZLiT1 (0.5 mol%), c) PLSZLiT2 (0.7 mol%), d) PLSZLiT3(0.9 mol%), and e) PLSZLiT4 (1 mol%)	90
Figure 4.29	FESEM microstructure of PLSZT ceramic with different amount of Li <sub>2</sub> CO <sub>3</sub> : a) 0 mol% , b) 0.5 mol% c) 0.7 mol% , d) 0.9 mol% , and e) 1 mol%	92
Figure 4.30	The variation in relative density of undoped and doped PLSZT	93
Figure 4.31	The bulk density and apparent porosity of undoped (inside a dotted box) and doped PLSZT ceramics with variation in $\text{Li}_2\text{CO}_3$ amount	94
Figure 4.32	The piezoelectric constant $(d_{33})$ of PLSZT ceramics with various amount of $\text{Li}_2\text{CO}_3$ dopant, where the blue dot is refer to the undoped PLZT	96
Figure 4.33	The electromechanical coupling factor $(k_p)$ of PLSZT ceramics with various amount of $\text{Li}_2\text{CO}_3$ dopant, where the blue dot is refer to the undoped PLZT	96
Figure 4.34	The quality mechanical factor $Q_m$ of PLSZT ceramics with various amount of $Li_2CO_3$ dopant, where the blue dot is refer to the undoped PLZT	97

Figure 4.35	The frequency dependence of the dielectric constant at 1 MHz to 1 GHz for PLSZT ceramics with various amount of Li <sub>2</sub> CO <sub>3</sub> dopant	99
Figure 4.36	The tangent loss of PLSZT ceramics with different amount of $\text{Li}_2\text{CO}_3$	100
Figure 4.37	Enlarge image of dielectric constant at 1 MHZ to 100 MHz for PLSZT ceramics with various amount of Li <sub>2</sub> CO <sub>3</sub> dopant	101
Figure 4.38	The relative permittivity and loss tangent at 1MHz of PLSZT ceramics with different amount of Li <sub>2</sub> CO <sub>3</sub>	102

### LIST OF SYMBOLS

k<sub>p</sub> Electromechanical Coupling Factor

 $\epsilon_{r}$  Dielectric Permittivity

ε<sub>o</sub> Permittivity Vacuum

ε" Imaginary Component of Permittivity

ε' Real Component of Permittivity

d<sub>33</sub> Piezoelectric Constant

tanδ Loss Tangent

Q<sub>m</sub> Quality Mechanical Factor

°C Degree Centigrade

μm Micrometer

g Gram

cm Centimeter

MHz Mega Hertz

GHz Giga Hertz

P<sub>r</sub> Remenant Polarization

pC/N Pico-Coulombs Newton

T<sub>c</sub> Curie Temperature

### LIST OF ABBREVIATIONS

BE Backscattered Electron

B-PZT  $Pb-Ba(Zr,Ti)O_3$ 

DTA Differential Thermal Analysis

FESEM Field Emission Scanning Electron Microscopy

ICDD International Center for Diffraction Data

LBC Li<sub>2</sub>O-Bi<sub>2</sub>O<sub>3</sub>-CdO

LBO  $Bi_2O_3$ - $Li_2CO_3$ 

MPB Morphotropic Phase Boundary

PT Lead Titanate

PLZT Lead Lanthanum Zirconate Titanate

PLSZT Lead Lanthanum Strontium Zirconate Titanate

PLSZLiT Lead Lanthanum Strontium Zirconate Lithium Titanate

PNN-PT-PZ  $PbNi_{1/3}Nb_{2/3}O_3$ -PbTiO<sub>3</sub>-PbZrO<sub>3</sub>

PSZT Lead Strontium Zirconate Titanate

PZN-PZT  $Pb(Zn_{1/3}Nb_{2/3})O_3-Pb(Zr_{0.49}Ti_{0.51})O_3$ 

 $PZT-PZN-PMnN \qquad Pb(ZrTi)O_3-Pb(Zn_{1/3}Nb_{2/3})O_3-Pb(Mn_{1/3}Nb)O_3$ 

PZ Lead Zirconate

PZT Lead Zirconate Titanate

SE Secondary Electron

TGA Thermogravimetry Analysis

XRD X-ray Diffractometer

### KESAN PENAMBAHAN Li<sub>2</sub>CO<sub>3</sub> KE ATAS SIFAT-SIFAT PIEZOELEKTRIK DAN DIELEKTRIK SERAMIK Pb<sub>0.93</sub>La<sub>0.02</sub>Sr<sub>0.05</sub>(Zr<sub>0.52</sub>Ti<sub>0.48</sub>)O<sub>3</sub>

#### **ABSTRAK**

Plambum zirkonat titanat (PZT) adalah yang paling banyak diselidiki di kalangan seramik perovskite berasaskan plambum. Sifat-sifat piezoelektrik dan dielektriknya kerap diubahsuai dengan berlainan dopan. Apabila PZT di dop dengan La<sup>3+</sup>dan Sr<sup>2+</sup>, pemalar dielektrik ( $\varepsilon_r$ ) dan pemalar piezoelektrik ( $d_{33}$ ) meningkat dengan sedikit peningkatan dalam factor pengganding planar  $(k_p)$ . Walau bagaimanapun,  $\varepsilon_r$  dan  $k_p$ yang tinggi adalah dikehendaki untuk peranti-peranti elektromekanikal seperti kipas piezoelektrik. Dalam penyelidikan ini, seramik Pb<sub>0.93</sub>La<sub>0.02</sub>Sr<sub>0.05</sub>(Zr<sub>0.52</sub>Ti<sub>0.48</sub>)O<sub>3</sub> (PLSZT) di dop dengan Li<sub>2</sub>CO<sub>3</sub> untuk dikaji kesannya ke atas sifat-sifat piezoelektrik dan dielektrik. Seramik ini telah disintesis dengan pengisar bebola planet bertenaga tinggi di dalam udara biasa selama 40 jam dan masing-masing disinter pada suhu yang agak rendah dari 1150 °C ke 850 °C selama 3 jam. Penambahan Li<sub>2</sub>CO<sub>3</sub> ke dalam PLSZT meningkatkan penumpatan seramik ini dan purata saizbutir. Maka mengukuhkan sifat-sifat piezoelektrik dan dielektrik seramik PLSZT. Nilai terbaik sifat-sifat piezoelektrik dan dielektrik PLSZT diperolehi bila di dop dengan 0.7 mol% Li<sup>+</sup>. Ketumpatannya ialah 7.420 g/cm<sup>3</sup>, k<sub>p</sub> ialah 0.461, d<sub>33</sub> ialah 259 pC/N, ialah 1270 dan tan  $\delta$  ialah 0.084.

### EFFECT OF ${\rm Li_2CO_3}$ ADDITION ON THE PIEZOELECTRIC AND DIELECTRIC PROPERTIES OF Pb<sub>0.93</sub> ${\rm La_{0.02}Sr_{0.05}}({\rm Zr_{0.52}Ti_{0.48}}){\rm O_3}$ CERAMICS

### **ABSTRACT**

Lead zirconate titanate (PZT) is the most widely investigated amongst lead-based perovskite ceramics. Its piezoelectric and dielectric properties are always modified with different dopants. When PZT doped with La<sup>3+</sup> and Sr<sup>2+</sup>, the piezoelectric constant (d<sub>33</sub>) and dielectric constant ( $\varepsilon_r$ ) are increase with slightly increase in electromechanical coupling factor  $(k_p)$ . However, high  $k_p$  and  $\epsilon_r$  is desirable for electromechanical devices such as piezoelectric fan. In this research Pb<sub>0.93</sub>La<sub>0.02</sub>Sr<sub>0.05</sub>(Zr<sub>0.52</sub>Ti<sub>0.48</sub>)O<sub>3</sub> (PLSZT) ceramic is doped with Li<sub>2</sub>CO<sub>3</sub> to investigate its effect on piezoelectric and dielectric properties. The ceramic was synthesized by high energy planetary ball milling in air for 40 hours and sintered at relatively low temperatures from 1150 °C to 850 °C for 3 hour, respectively. The addition of Li<sub>2</sub>CO<sub>3</sub> in PLSZT improved the densification of the ceramics and increases the average grain size. Thus, piezoelectric and dielectric properties are enhanced with the increase of Li+ content. The best piezoelectric and dielectric properties were obtained for 0.7 mol% Li<sup>+</sup> doped PLSZT ceramics. The density is 7.420 g/cm<sup>3</sup>, k<sub>p</sub> is 0.461,  $d_{33}$  is 259 pC/N,  $\varepsilon_r$  is 1270, and tan  $\delta$  is 0.084 is observed.

### **CHAPTER ONE**

### INTRODUCTION

### 1.1 Background

Ceramics are defined as non-metallic inorganic solids which are bonded together by multiple bonds such as ionic and covalent bond. The word ceramic is derived from Greek word "keramos" which means "potters clay". Precisely, the word keramos is originated from the Sanskrit language which means "to burn" (Carter & Norton, 2007). On the basis of raw materials, the ceramics are classified into two classes' i.e. traditional ceramics and advanced ceramics. Traditional ceramics are produced by naturally occurring raw materials. While advanced ceramics are synthesized by chemical processing routes or from synthetic raw materials.

Electroceramics are the advanced ceramic materials whose electrical and magnetic properties are prime focus for the applications. The history of electroceramics begins in 1940, when the Al<sub>2</sub>O<sub>3</sub> were used in the spark plugs as an insulator. Nowadays, numerous materials are used in different electronic and magnetic applications. For example, zinc oxide in varistors, barium titanate in capacitors, tin oxide in gas sensors, lithium niobate in electro-optic devices and lead zirconium titanate in piezoelectric devices are commonly used (Segal, 1991).

To date, lead zirconium titanate (PZT) is one of the most widely studied electroceramics. PZT is a solid solution of the antiferroelectric lead zirconate

(PbZrO<sub>3</sub>), and ferroelectric lead titanate (PbTiO<sub>3</sub>). It has a nearly cubic perovskite crystal structure with general formula ABO<sub>3</sub>, where A<sup>2+</sup> site contains Pb<sup>2+</sup> and B<sup>4+</sup> site contains Ti<sup>4+</sup> and Zr<sup>4+</sup> ions. The body centered B<sup>4+</sup> cation is surrounded by a corner linked octahedral oxygen network. Where, A<sup>2+</sup> cation is located at the corner of cubic unit (Galasso, 2013). Due to lack of center of symmetry in crystal structure, it exhibits the piezoelectric effect. By definition, piezoelectricity is an ability of the crystal to develop an electric displacement upon the mechanical stress which is also known as a direct piezoelectric effect. Piezoelectric material also undergoes mechanical deformation on the application of electric field which is known as converse effect. Ferroelectricity is a sub class of piezoelectricity in which the polarization occurs spontaneously and the dipoles can be reoriented under an applied electric field. The reorientation of polarization in a material is called poling process. Due to this poling process, the piezoelectric effect can be utilized in a ferroelectric ceramics.

Number of ferroelectric ceramics such as BaTiO<sub>3</sub>, Pb(Zr,Ti)O<sub>3</sub>, PbLa(ZrTi)O<sub>3</sub>, PbN<sub>2</sub>O<sub>6</sub> and PbTiO<sub>3</sub> are known for piezoelectric applications. In early 1940, the BaTiO<sub>3</sub> was extensively used but nowadays it is largely replaced by PZT. This is because PZT is easily poled, having high electromechanical coupling coefficient, has high Tc (Curie temperature), and has wide range of dielectric constant. These exceptional piezoelectric properties are optimum at near to the morphotropic phase boundary (MPB). MPB is the region that shows an abrupt structural change within a solid solution. The variation in composition around the MPB region greatly affects the materials property.

PZT is always modified with dopants to further improve and optimize its basic properties required for a specific application. Usually dopant is incorporated in the parent material within the concentration of  $\leq 3$  at.% (Haertling, 1999). Doped PZT are divided into two groups, i.e. hard PZT and soft PZT, on the basis of the effect that dopant induces on PZT. These effects are mainly depends on the charge of dopants. According to the charge they carry, the dopants are further classified into three classes i.e. acceptor, donor and isovalent. Since the discovery of the PZT, numerous dopants were added for the enhancement of piezoelectric properties e.g. Nb<sup>5+</sup>(Chu et al., 2004), Gd<sup>3+</sup>(Parashar et al., 2004), Sr<sup>2+</sup>, La<sup>3+</sup>, Li<sup>+</sup>(Tiwari & Srivastava, 2015), W<sup>3+</sup>(Bochenek & Zachariasz, 2015), Sm<sup>3+</sup>, Nd<sup>3+</sup> and rare earth elements (Eu<sup>3+</sup>, Dy<sup>3+</sup>, Er<sup>3+</sup>, and Yb<sup>3+</sup>) (Shannigrahi et al., 2004).

PZT is generally synthesized by conventional solid state reaction and sintered at high temperature around 1200 °C or above. But too high temperature is not suitable for Pb<sup>2+</sup> containing materials, which is due to the high volatility of Pb<sup>2+</sup>. The loss of Pb<sup>2+</sup> from the PZT ceramic eventually affects the useful properties of the material such as electrical, mechanical and optical. Several attempts have been made to successfully densify the PZT material at relatively low temperature. The main approaches that have been employed for that purpose are the use of ultra fine powders and the addition of sintering aids. For ultra fine powders, the submicron or nanosized powders have been synthesized by mechanochemical alloying technique which is also known as high energy ball milling. As compared it to other processing routes, it gives several advantages. Firstly, the widely available oxides are used as

the starting materials. Secondly, it is a simpler process due to single firing step. Furthermore, it takes place in a sealed container at room temperature, thus avoid the loss of volatile Pb<sup>2+</sup> (Kong et al., 2008). As the Pb<sup>2+</sup> loss occurred at elevated temperature, excess PbO powder intentionally added during batch preparation for two reasons. Firstly, to enhance densification by forming a PbO rich liquid during sintering process. Secondly, it is added to compensate the evaporation of PbO during calcinations and sintering (Song et al., 1989).

Piezoelectric materials especially PZT is widely used as actuators and sensors in modern technologies such as accelerometers, microphones, micromotors, and micropumps. The type of piezoelectric actuators which is used for cooling applications is known as piezoelectric fan (Liu et al., 2013). It is mainly employed in compact and portable microelectronic devices for thermal management. In electronic devices, the thermal management is an important task to prevent electronic circuit from the adverse effect of heat. Previously, the conventional cooling system, such as rotary fan and heat sink were used for thermal management in electronic devices (e.g. personal computers). In recent years, the electronic industry is moving towards the compact and portable microelectronic devices which results in generating the smaller electronic components. These compact microelectronic devices experience a heat generation. Due to constrained and small space within the electronic package, the heat removal becomes a challenge.

### 1.2 Problem Statement

Lead zirconate titanate (PZT) is a well known piezoelectric material in the field of electroceramics. Its exceptional piezoelectric properties made it dominant among other ferroelectric materials. It is extensively used in the wide range of electronic applications, such as in sensors, transducers, and actuators (Setter & Waser, 2000). PZT always modified with dopants for further improvising the electrical properties  $d_{33}$  (piezoelectric constant),  $\varepsilon_r$  (relative permittivity) and  $k_p$  (electromechanical coupling factor) that is required for specific application. Numerous donor dopants (Nb, Nd, La, and rear earth metals) have been added to PZT ceramics to tailoring its piezoelectric and dielectric properties. Amongst these dopants  $La^{3+}$  was extensively studied. Incorporation of  $La^{3+}$  ion produce a profound effect on dielectric properties ( $\varepsilon_r$ ), due to the growth inhibition caused the degradation of  $k_p$  (Pdungsap et al., 2005; Sharma et al., 2006; Sahoo& Panda, 2013). The literature on the improvising the  $k_p$  of PZT was not clearly visible.

The  $k_p$  of piezoelectric ceramics have been studied by some researchers. Kulcsar (1959) studied the individual effect of  $Sr^{2+}$  and  $Ca^{2+}$  on electromechanical properties of the PZT. The profound effect was observed on  $\epsilon_r$  but the  $k_p$  is only slightly increased from 0.48 to 0.51, which is attributed to the reduction in the distortion from cubic symmetry to rhombohedral. Nasar et al. (2002) had investigated theoretically and experimentally the effect of  $Sr^{2+}$  on the remanent polarization  $(P_r)$  and  $k_p$  of the PZT ceramics. The addition of  $Sr^{2+}$  minimizes the energy of rhombohedral phase, which ease the transformation of phases and hence increase the  $k_p$  value. For most of the electroceramic applications the high  $\epsilon_r$  and  $k_p$ 

are desired in combination such as for piezoelectric fan application. For this purpose PZT ceramic was co-doped with  $Sr^{2+}$  and  $La^{3+}$  by few researches. Kalem et al. (2011) studied the co-doped PZT system with  $Sr^{2+}$ ,  $La^{3+}$  and varied the concentration of both dopants and Zr/Ti ratio. The author found that at a lower concentration of  $La^{3+}$ , the piezoelectric properties ( $k_p$  and  $d_{33}$ ) were increased, while at a higher  $La^{3+}$  content, the  $k_p$  was decreased due to growth inhibition. In case of varying the  $Sr^{2+}$  content the  $k_p$  value was increased up to 0.56. Similar material (PZT with  $La^{3+}$  and  $Sr^{2+}$ ) was investigated by Bahanurddin et al. (2015b) via high energy planetary ball mill to enhance the piezoelectric properties by avoiding evaporation of PO from the ceramic at elevated sintering temperature. The material exhibits high dielectric constant ( $\varepsilon_r = 5360$ ). However, its piezoelectric properties ( $k_p$  and  $d_{33}$ ) were not mentioned and the sintering temperature was not much lower. The volatilization of PbO from the ceramic during thermal treatment is another major issue which associated with the PZT (Kong et al., 2002). The loss of PbO fluctuate the electrical, optical and mechanical properties of the PZT ceramics (Garg et al., 1999; Song et al., 1989).

To overcome both the issues i.e. optimizing the  $k_p$  value and avoid the PbO loss of PZT ceramic for piezoelectric fan application. The dopant should be added which enhance the piezoelectric properties especially ( $k_p$  and  $\epsilon_r$ ) and reduces the sintering temperature without deteriorated the properties. Recently,  $k_p$  was enhanced by incorporating Li<sub>2</sub>CO<sub>3</sub> in PZT system at low sintering temperature by many researchers (Hou et al., 2007; Vuong and Gio, 2013; Zeng et al., 2013; Fan et al., 2014). The increment in the  $k_p$  with other piezoelectric properties was due to the incorporation of Li<sup>+</sup> into crystal lattice. The Li<sup>+</sup> ions tend to occupy the octahedral sites of the lattice, which leads to the formation of additional anionic vacancies. The

formation of these vacancies results in lattice distortion by lengthened the c-axis. Hence,  $Li_2CO_3$  is appropriate candidate to enhance the  $k_p$  of the PZT material. Furthermore, it acts as a sintering aid (Wang et al., 1992). Due to its low melting point of  $Li_2CO_3$  (723 °C) the liquid phase form which cover and wet the grains and therefore, improves the densification of the material at low sintering temperature. In later stage it reabsorbs into the lattice and modifies the properties. In the present work, PZT material which was previously doped with  $La^{3+}$  and  $Sr^{2+}$  is further doped with  $Li^+$ . The material is synthesized via high energy planetary ball milling to avoid PbO lost. Therefore, it is believed that the incorporation of  $Li^+$  in PLSZT (Pb<sub>0.93</sub> $La_{0.02}Sr_{0.05}(Zr_{0.52}Ti_{0.48})O_3$ ) system coupled with synthesized using high energy planetary ball milling could further enhance its piezoelectric properties especially  $k_p$ .

### 1.3 Objectives of the Research

The objectives of this research are:

- To synthesize PLSZT (PZT doped with La<sup>3+</sup> and Sr<sup>2+</sup>) and determine its dielectric and piezoelectric properties.
- $\bullet$  To synthesize PLSZLiT (PLSZT doped with Li<sub>2</sub>CO<sub>3</sub>) at low temperature via high energy planetary ball milling.
- To determine the effect of Li<sub>2</sub>CO<sub>3</sub> on the piezoelectric and dielectric properties of the PLSZT.

### 1.4 Thesis Structure

The work described in this thesis is organized into five chapters. Chapter 1 gives an overview of the ceramics and especially on the piezoelectric properties of the PZT electroceramic. In addition the affect of dopants and processing route on the piezoelectric properties of the PZT material are outlined. Finally, the problem associated with the piezoelectric and dielectric properties of the material, which required for thermal management of portable electronic devices by piezoelectric fan and the objectives of this study are presented.

Chapter 2 reviews the history of piezoelectricity and ferroelectricity. In addition the piezoelectric properties to measure the piezoelectric effect in the ferroelectric material are discussed. The previous work in La<sup>3+</sup>, Sr<sup>2+</sup> and Li<sup>+</sup> doped and undoped PZT is reviewed. The effects of dopants on the piezoelectric properties of the PZT material are discussed in details. In addition, the approaches that adopted to densify the PZT material at low sintering temperature are also including in this chapter.

Chapter 3 describes the processing route and other steps, which is adopted to synthesize the doped and undoped PZT. Furthermore, different characterization techniques which were used for the analysis of the synthesized material are also present in this chapter. Finally, the sample preparation, equipments and the methods that were used to measure the piezoelectric properties such as  $\varepsilon_r$ , tan  $\delta$ ,  $d_{33}$ ,  $K_P$ , and mechanical quality factor are discussed in this chapter.